TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX541F,TC74LCX541FW,TC74LCX541FT,TC74LCX541FK

Low-Voltage Octal Bus Buffer with 5-V Tolerant Inputs and Outputs

The TC74LCX541F/FW/FT/FK is a high-performance CMOS octal bus buffer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

The device is designed for low-voltage $(3.3\ V)\ VCC$ applications, but it could be used to interface to $5\ V$ supply environment for both inputs and outputs.

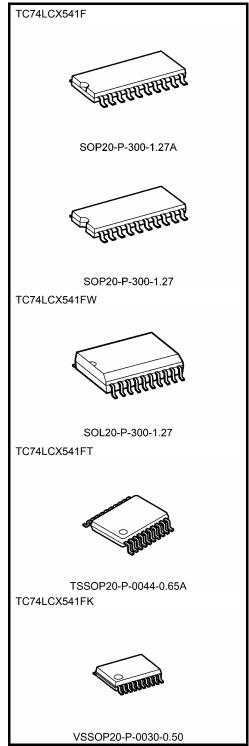
The TC74LCX541F/FW/FT is a non-inverting 3-state buffer having two active-low output enables. When either $\overline{\text{OE}}1$ or $\overline{\text{OE}}2$ are high, the terminal outputs are in the high-impedance state. This device is designed to be used with 3-state memory address drivers, etc.

All inputs are equipped with protection circuits against static discharge.

Features

- Low-voltage operation: VCC = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 6.5 \text{ ns (max)} (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Output current: $|I_{OH}|/I_{OL} = 24 \text{ mA (min)} (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: ±500 mA
- Available in JEDEC SOP, JEITA SOP and TSSOP
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 541 type

Note: xxxFW (JEDEC SOP) is not available in Japan.



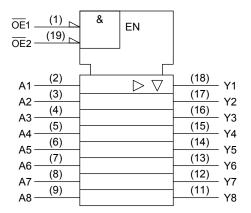
Weight

SOP20-P-300-1.27A : 0.22 g (typ.) SOP20-P-300-1.27 : 0.22 g (typ.) SOL20-P-300-1.27 : 0.46 g (typ.) TSSOP20-P-0044-0.65A : 0.08 g (typ.) VSSOP20-P-0030-0.50 : 0.03 g (typ.)

Pin Assignment (top view)

OE1 20 V_{CC} $\overline{\text{OE}}2$ Α1 2 19 A2 3 18 Y1 А3 Y2 4 17 Υ3 A4 5 16 Α5 6 15 Y4 7 Y5 Α6 14 Α7 8 13 Y6 Υ7 Α8 9 GND 10 Y8

IEC Logic Symbol



Truth Table

	Inputs					
OE1	OE2	An				
Н	Х	Х	Z			
Х	Н	Х	Z			
L	L	Н	Н			
L	L	L	L			

X: Don't care

Z: High impedance

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2006-06-01



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	−0.5 to 7.0	V
DC input voltage	V _{IN}	-0.5 to 7.0	٧
		-0.5 to 7.0 (Note 2)	
DC output voltage	V _{OUT}	-0.5 to $V_{CC} + 0.5$	V
		(Note 3)	
Input diode current	lıK	-50	mA
Output diode current	lok	±50 (Note 4)	mA
DC output current	lout	±50	mA
Power dissipation	PD	180	mW
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA
Storage temperature	T _{stg}	-65 to 150	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note 2: Output in OFF state

Note 3: High or low state. IOUT absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Recommended Operating Conditions (Note 1)

Characteristics	Symbol	Rating	Unit		
Power supply voltage	V _{CC}	2.0 to 3.6	V		
rower suppry voltage	vCC	1.5 to 3.6 (Note 2)	V		
Input voltage	V _{IN}	0 to 5.5	٧		
Output voltage	V	0 to 5.5 (Note 3)	V		
Output voltage	V _{OUT}	0 to V _{CC} (Note 4)	V		
Output current	la/la.	±24 (Note 5)	m۸		
Output current	I _{OH} /I _{OL}	±12 (Note 6)	mA		
Operating temperature	T _{opr}	-40 to 85	°C		
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V		

Note 1: The recommended operating conditions are required to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

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Note 2: Data retention only

Note 3: Output in OFF state

Note 4: High or low state

Note 5: $V_{CC} = 3.0 \text{ to } 3.6 \text{ V}$

Note 6: $V_{CC} = 2.7 \text{ to } 3.0 \text{ V}$

Note 7: $V_{IN} = 0.8$ to 2.0 V, $V_{CC} = 3.0$ V



Electrical Characteristics

DC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics		Cumbal	Symbol Test Condition			Min	May	Unit	
Character	Sucs	Symbol	rest Condition		V _{CC} (V)	IVIIII	Max	Unit	
Input voltage	H-level	V _{IH}		_	2.7 to 3.6	2.0	_	V	
input voltage	L-level	V _{IL}		_	2.7 to 3.6	_	8.0	v	
				$I_{OH} = -100 \mu A$	2.7 to 3.6	V _{CC} - 0.2	_		
	H-level	V _{OH}	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_		
				$I_{OH} = -18 \text{ mA}$	3.0	2.4	_		
Output voltage				$I_{OH} = -24 \text{ mA}$	3.0	2.2	_	V	
			V V 22V	I _{OL} = 100 μA	2.7 to 3.6	_	0.2		
	L-level			I _{OL} = 12 mA	2.7	_	0.4		
	L-level	L-level	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 16 mA	3.0	_	0.4	
				I _{OL} = 24 mA	3.0	_	0.55		
Input leakage currer	t	I _{IN}	V _{IN} = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μА	
3-state output off-sta	ite current	loz	$V_{IN} = V_{IH}$ or V_{IL} $V_{OLIT} = 0$ to 5.5 V		2.7 to 3.6	_	±5.0	μА	
Power off leakage co	urrent	l _{OFF}	V _{IN} /V _{OUT} = 5.5 V		0	_	10.0	μА	
			. V _{IN} = V _{CC} or GND		V _{IN} = V _{CC} or GND		_	10.0	
Quiescent supply cu	rrent	ICC	V _{IN} /V _{OUT} = 3.6 to 5.5 V		2.7 to 3.6	_	±10.0	μА	
Increase in I _{CC} per i	nput	Δlcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6	_	500		

AC Characteristics ($Ta = -40 \text{ to } 85^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Decree with a delection	t _{pLH}	Figure 4 Figure 0	2.7	_	7.5	
Propagation delay time	t _{pHL}	Figure 1, Figure 2	3.3 ± 0.3	1.5	6.5	ns
Outrout analys times	t _{pZL}	Figure 1, Figure 3	2.7	_	9.5	ns
Output enable time	t _{pZH}	Figure 1, Figure 3	3.3 ± 0.3	1.5	8.5	
Output disable time	t _{pLZ}	Figure 1, Figure 3	2.7		8.5	ns
Output disable time	t _{pHZ}	rigure 1, rigure 3	3.3 ± 0.3	1.5	7.5	110
Output to output skew	t _{osLH}	(Note)	2.7	1	1	ns
Carpar to output snew	t _{osHL}	(Note)	3.3 ± 0.3		1.0	110

Note: Parameter guaranteed by design.

 $(t_{\text{OSLH}} = |t_{\text{pLHm}} - t_{\text{pLHn}}|, \ t_{\text{OSHL}} = |t_{\text{pHLm}} - t_{\text{pHLn}}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500$ Ω)

Characteristics		Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic	V _{OL}	V _{OLP}	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.8	V
Quiet output minimum dynamic	V _{OL}	V _{OLV}	V _{IH} = 3.3 V, V _{IL} = 0 V	3.3	0.8	V

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Capacitive Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	C _{IN}	_	3.3	7	pF
Output capacitance	C _{OUT}	_	3.3	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Note) 3.3	40	pF

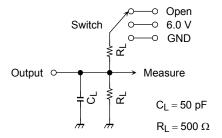
Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per bit)}$

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AC Test Circuit



Parameter	Switch
t _{pLH} , t _{pHL}	Open
t _{pLZ} , t _{pZL}	6.0 V
t _{pHZ} , t _{pZH}	GND

Figure 1

AC Waveform

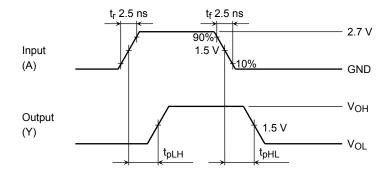


Figure 2 t_{pLH}, t_{pHL}

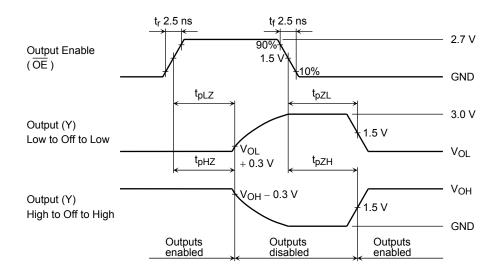
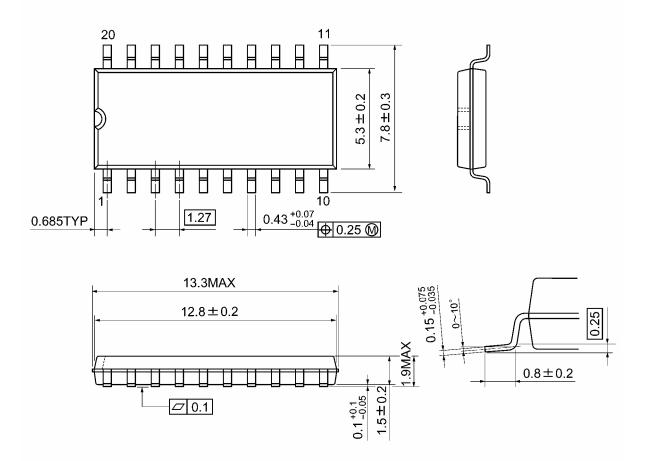


Figure 3 t_{pLZ} , t_{pHZ} , t_{pZL} , t_{pZH}

Package Dimensions

SOP20-P-300-1.27A Unit: mm

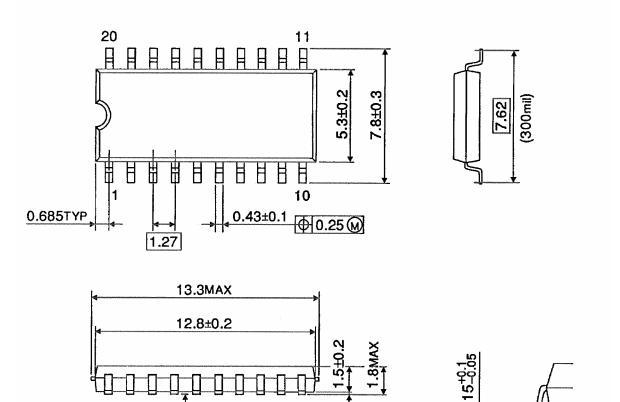


Weight: 0.22 g (typ.)

0.8±0.2

Package Dimensions

SOP20-P-300-1.27 Unit: mm

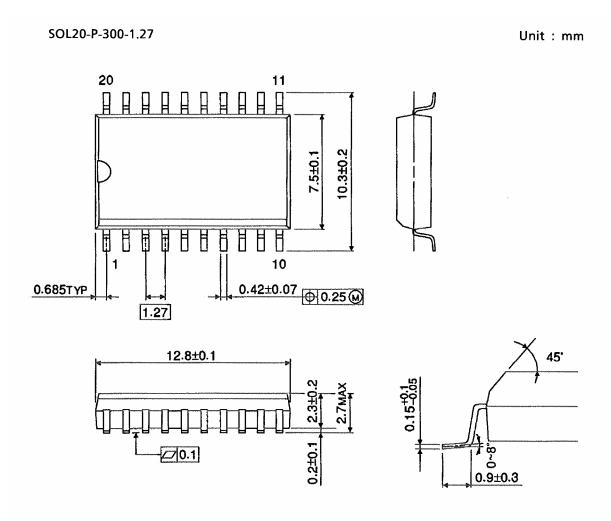


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Weight: 0.22 g (typ.)

Package Dimensions (Note)

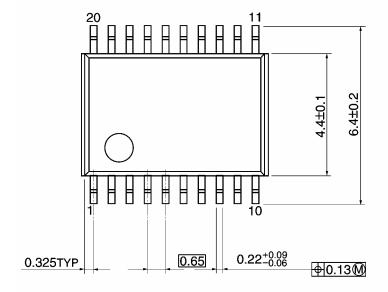


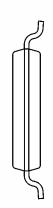
Note: This package is not available in japan.

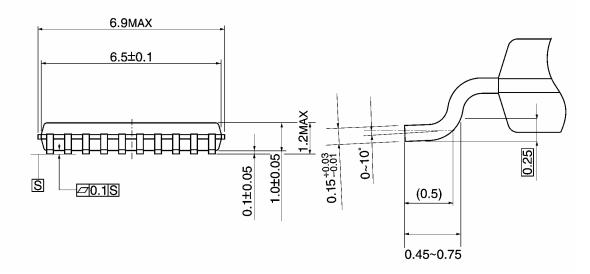
Weight: 0.46 g (typ.)

Package Dimensions

TSSOP20-P-0044-0.65A Unit: mm



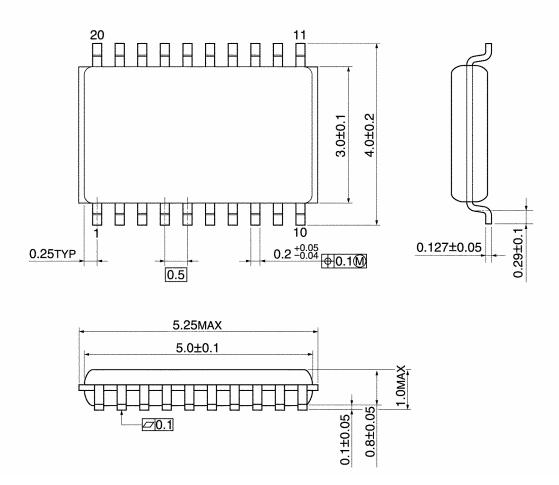




Weight: 0.08 g (typ.)

Package Dimensions

VSSOP20-P-0030-0.50 Unit: mm



Weight: 0.03 g (typ.)

Note: Lead (Pb)-Free Packages

SOP20-P-300-1.27A TSSOP20-P-0044-0.65A VSSOP20-P-0030-0.50

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